

1. General Description

The EM74HCS09 is a quad 2-input AND gate with open-drain outputs and Schmitt-trigger inputs. Schmitt trigger inputs transform slowly changing input signals into sharply defined jitter-free output signals.

2. Features and Benefits

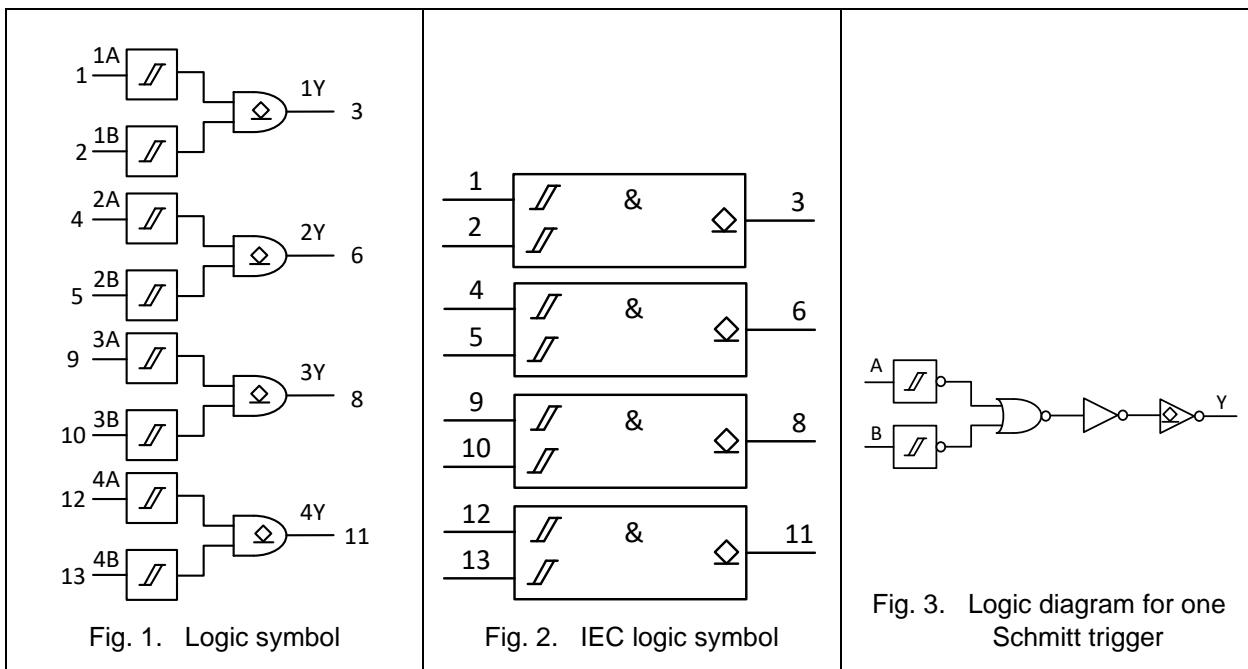
- Wide supply voltage range from 2.0 V to 6.0 V
- High noise immunity
- CMOS low power dissipation
- Latch-up performance exceeds 250 mA
- Unlimited rise and fall times
- Complies with JEDEC standards:
 - JESD8C (2.7 V to 3.6 V)
 - JESD7A (2.0 V to 6.0 V)
- ESD protection:
 - HBM ANSI/ESDA/JEDEC JS-001 Class 2 exceeds 3500 V
 - CDM ANSI/ESDA/JEDEC JS-002 Class C3 exceeds 2000 V
- Multiple package options

3. Ordering Information

Table 1. Ordering information

Type number	Package		
	Name	Description	Quantity
EM74HCS09D	SOP-14L	plastic small outline package; 14 leads; body width 3.9 mm	3000
EM74HCS09PW	TSSOP-14L	plastic thin shrink small outline package; 14 leads; body width 4.4 mm	3000

4. Function Diagram



5. Pinning Information

5.1. Pinning

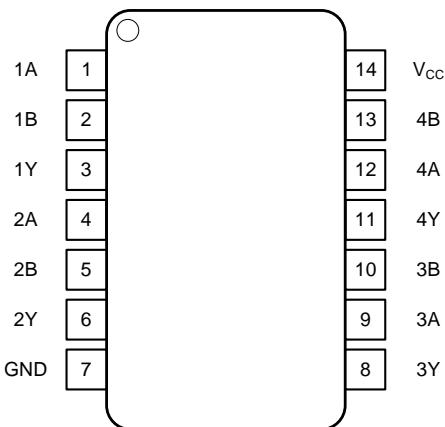


Fig. 4. Top view pin configuration SOP and TSSOP

5.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
1A, 2A, 3A, 4A	1, 4, 9, 12	Data input
1B, 2B, 3B, 4B	2, 5, 10, 13	Data input
1Y, 2Y, 3Y, 4Y	3, 6, 8, 11	Data output
GND	7	Ground (0V)
Vcc	14	Supply voltage

6. Functional Description

Table 3. Function table

H = HIGH voltage level; L = LOW voltage level.

Control		Output
nA	nB	nY
L	L	L
L	H	L
H	L	L
H	H	H

7. Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Table 4. Absolute Maximum Ratings

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND.

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	7.0	V
I _{IK}	input clamping current	V _I < -0.5 V or V _I > V _{CC} + 0.5 V [1]		±20	mA
I _{OK}	output clamping current	V _O < -0.5 V or V _O > V _{CC} + 0.5 V [1]		±20	mA
V _O	output voltage		-0.5	V _{CC} + 0.5 V	V
I _O	output current	V _O = -0.5 V to (V _{CC} + 0.5 V)		±35	mA
I _{CC}	supply current			70	mA
I _{GND}	ground current		-70		mA
P _{TOT}	total power dissipation			500	mW
T _{STG}	storage temperature		-65	150	°C

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

8. Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. EnergyMath does not recommend exceeding them or designing to Absolute Maximum Ratings.

Table 5. Recommended Operating Conditions

Symbol	Parameter	Conditions	EM74HCS09			Unit
			Min	Typ	Max	
V _{CC}	supply voltage		2.0	5.0	6.0	V
V _I	input voltage		0		V _{CC}	V
V _O	output voltage		0		V _{CC}	V
T _{AMB}	ambient temperature		-40		125	°C

9. Static Characteristics

Table 6. Static characteristics

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V). Typical values measured at $T_{amb} = 25^\circ\text{C}$ (unless otherwise noted).

Symbol	Parameter	Conditions	-40 °C to +85 °C			-40 °C to +125 °C		Unit
			Min	Typ	Max	Min	Max	
V_{OL}	LOW-level output voltage	$V_I = V_{T+}$ or V_{T-}						
		$I_O = 20 \mu\text{A}; V_{CC} = 2.0 \text{ V}$			0.1		0.1	V
		$I_O = 20 \mu\text{A}; V_{CC} = 4.5 \text{ V}$			0.1		0.1	V
		$I_O = 20 \mu\text{A}; V_{CC} = 6.0 \text{ V}$			0.1		0.1	V
		$I_O = 6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$			0.33		0.4	V
		$I_O = 7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$			0.33		0.4	V
I_I	input leakage current	$V_I = V_{CC}$ or GND ; $V_{CC} = 6.0 \text{ V}$			± 1		± 1	μA
I_{OZ}	OFF-state output current	$V_I = V_{T+}$ or V_{T-} ; $V_O = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$			± 5		± 10	μA
I_{CC}	supply current	$V_I = V_{CC}$ or GND ; $I_O = 0 \text{ A}$; $V_{CC} = 6.0 \text{ V}$			1		2	μA
C_I	input capacitance			7				pF

10. Dynamic Characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 6. Typical values measured at $T_{amb} = 25^\circ\text{C}$ (unless otherwise noted).

Symbol	Parameter	Conditions	-40 °C to +85 °C			-40 °C to +125 °C		Unit
			Min	Typ	Max	Min	Max	
t_{pd}	propagation delay	nA, nB to nY; see Fig. 5 [1]						
		$V_{CC} = 2.0 \text{ V}$			35		40	ns
		$V_{CC} = 4.5 \text{ V}$			20		25	ns
		$V_{CC} = 6.0 \text{ V}$			15		20	ns
t_t	transition time	see Fig. 5 [2]						
		$V_{CC} = 2.0 \text{ V}$			9		11	ns
		$V_{CC} = 4.5 \text{ V}$			6		8	ns
		$V_{CC} = 6.0 \text{ V}$			4		5	ns
C_{PD}	power dissipation capacitance	$C_L = 15 \text{ pF}; f = 1 \text{ MHz}; V_i = \text{GND to } V_{CC}$ [3]		6				pF

[1] t_{pd} is the same as t_{PZL} and t_{PLZ} .

[2] t_t is the same as t_{THL} and t_{TLH} .

[3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum(C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

f_i = input frequency in MHz;

f_o = output frequency in MHz;

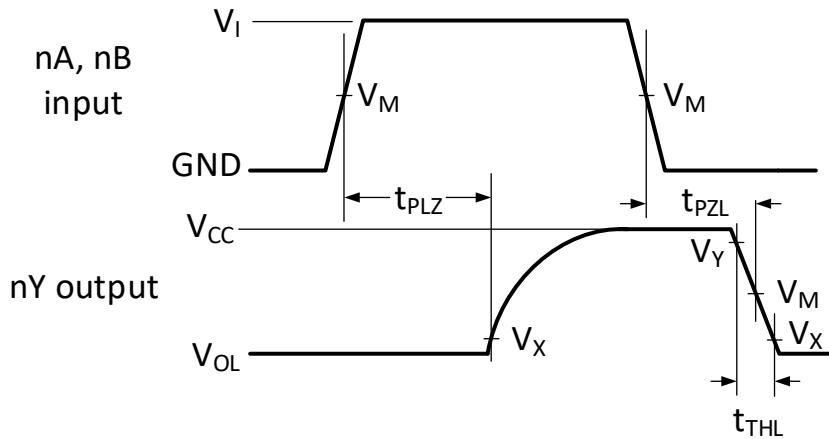
C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

$\sum(C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.

10.1. Waveforms and test circuit



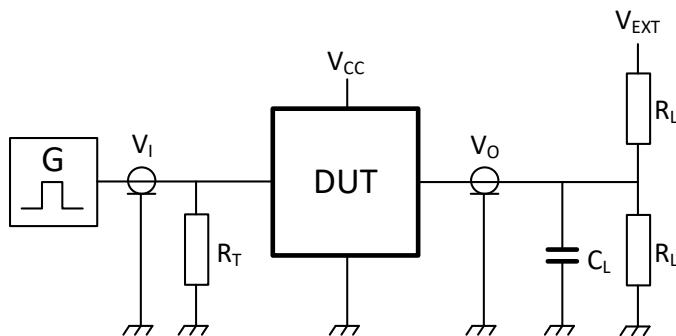
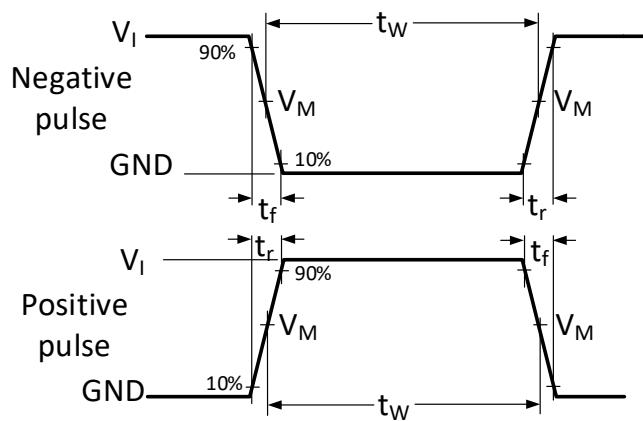
Measurement points are given in Table 8.

V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig. 5. The input to output propagation delays

Table 8. Measurement points

Type	Input	Output		
	V_M	V_M	V_X	V_Y
EM74HCS09	$0.5V_{CC}$	$0.5V_{CC}$	$0.1V_{CC}$	$0.9V_{CC}$

EM74HCS09
Quad 2-input AND Schmitt trigger with open-drain outputs


Test data is given in Table 9.

Definitions for test circuit:

R_L = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

R_T = Termination resistance should be equal to the output impedance Z_o of the pulse generator.

V_{EXT} = External voltage for measuring switching times.

Fig. 6. Test circuit for measuring switching times

Table 9. Test data

Type	Input		Load		V_{EXT}
	V_I	$t_r = t_f$	C_L	R_L	
EM74HCS09	V_{CC}	$\leq 2.5 \text{ ns}$	15 pF	500Ω	open

11. Transfer Characteristics

Table 10. Transfer characteristics

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V). Typical values are measured at $T_{amb} = 25^\circ\text{C}$.

Symbol	Parameter	Conditions	-40 °C to +85 °C			-40 °C to +125 °C			Unit
			Min	Typ	Max	Min	Max		
V_{T+}	positive-going threshold voltage	see Fig. 7 and Fig. 8							
		$V_{CC} = 2.0 \text{ V}$	0.7	1.21	1.5	0.7	1.5		V
		$V_{CC} = 4.5 \text{ V}$	1.7	2.39	3.15	1.7	3.15		V
		$V_{CC} = 6.0 \text{ V}$	2.1	3.05	4.2	2.1	4.2		V
V_{T-}	negative-going threshold voltage	see Fig. 7 and Fig. 8							
		$V_{CC} = 2.0 \text{ V}$	0.3	0.6	0.9	0.3	0.9		V
		$V_{CC} = 4.5 \text{ V}$	0.9	1.41	2.0	0.9	2.0		V
		$V_{CC} = 6.0 \text{ V}$	1.2	1.9	2.6	1.2	2.6		V
V_H	hysteresis voltage	see Fig. 7 and Fig. 8							
		$V_{CC} = 2.0 \text{ V}$	0.2	0.61	1.0	0.2	1.0		V
		$V_{CC} = 4.5 \text{ V}$	0.4	0.97	1.4	0.4	1.4		V
		$V_{CC} = 6.0 \text{ V}$	0.6	1.16	1.6	0.6	1.6		V

11.1. Waveforms transfer characteristics

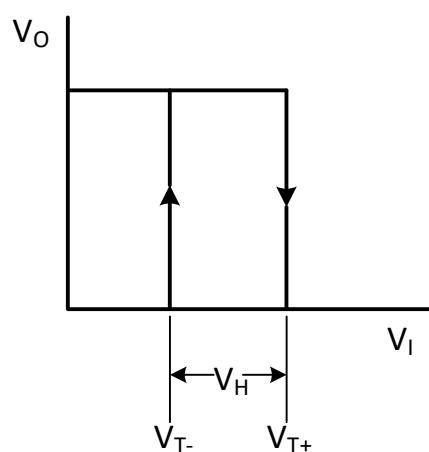
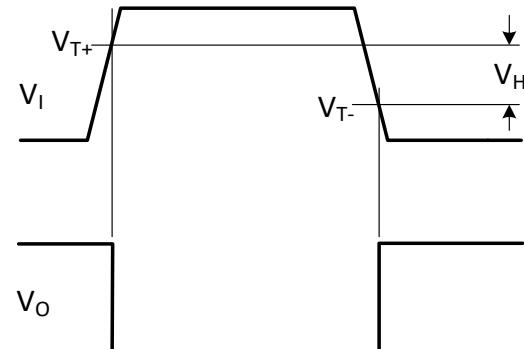


Fig. 7. Transfer characteristic

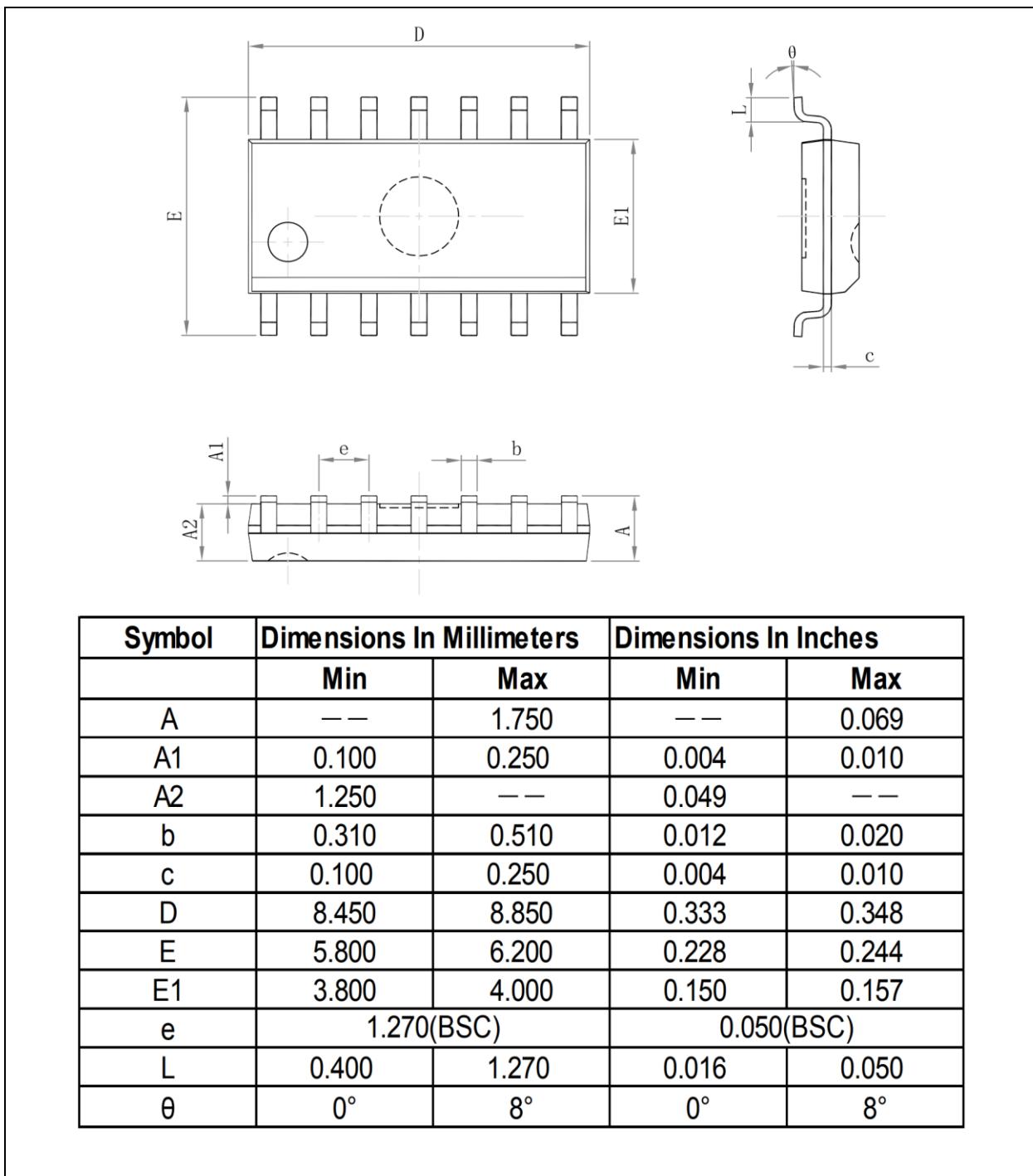


V_{T+} and V_{T-} limits at 70% and 20%.

Fig. 8. Definition of V_{T+} , V_{T-} and V_H

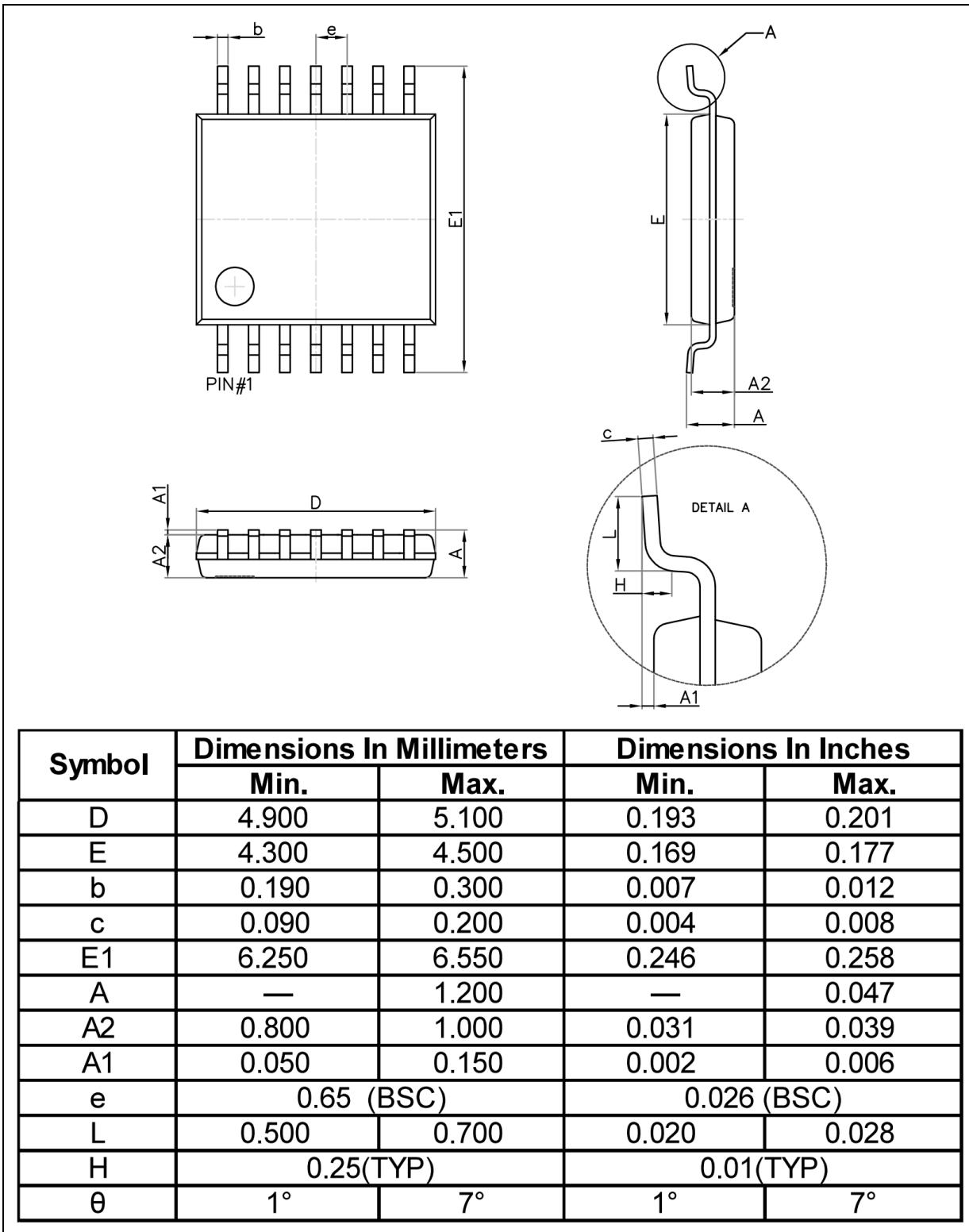
12. Package Outline

SOP-14L



EM74HCS09

Quad 2-input AND Schmitt trigger with open-drain outputs

TSSOP-14L


13. Abbreviations

Table 11. Abbreviations

Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
CDM	Charged Device Model

14. Revision History

Table 12. Revision history

Document ID	Release Date	Data sheet status	Change notice	Supersedes
EM74HCS09 Rev. 1.0	Aug 30, 2024	Product datasheet		